



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Sang-jin PARK, et al.

Art Unit:

2818

Serial No.

10/830,119

Examiner:

Mai Huong C. TRAN

Filed:

April 23, 2004

Confirmation No.

9008

For:

MAGNETIC RANDOM ACCESS MEMORY
INCLUDING MIDDLE OXIDE LAYER AND
METHOD OF MANUFACTURING THE SAME

SUPPLEMENT TO INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.56 FILED AUGUST 8, 2005

Commissioner for Patents Alexandria, VA 22313-1450

Sir:

Supplementing the IDS filed August 8, 2005, there is submitted herewith an English language abstract for KR 2003 001 106, a complete copy of the Korean language document having been submitted with said IDS on August 8, 2005.

STATEMENT OF RELEVANCE

Relevance of the non-English language reference is as follows: An English language Search Report, indicating the degree of relevance found by the foreign office, accompanied the IDS filed August 8, 2005, thereby satisfying the requirement for a concise explanation. See MPEP 609(A)(3).

CERTIFICATION

The undersigned hereby certifies in accordance with 37 CFR §1.97(e)(1) that KR 003 001 106 of information contained in this Information Disclosure Statement was cited in a

communication from a foreign patent office in a counterpart foreign application not more than three

(3) months prior to the filing of this Statement. [Box checked if applicable.]

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Respectfully submitted,

August 10, 2005 Date

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DEPOSIT ACCOUNT CHARGE AUTHORIZATION

If fee payment is enclosed, this amount is believed to be correct. However, the Director is hereby authorized to charge any deficiency or credit any overpayment to Deposit Account No. 50-1645.

Any additional fee(s) necessary to effect the proper and timely filing of the above-paper may also be charged to Deposit Account No. 50-1645.